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7,456,430 B1 09/544,801 11/25/2008 04/07/2000 1717 SEL 174

Respectfully Submitted,

Mark J. Murphy Registration No. 34,225 Date: December 11, 2008

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## (12) United States Patent

## Yamazaki et al.

## (54) SEMICONDUCTOR DEVICE AND METHOD FOR FABRICATING THE SAME

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- (52) **U.S. Cl. 257/72**; 257/59; 257/347; 257/350; 257/351; 257/344; 257/E27.111; 257/E29.275; 257/E29.278

See application file for complete search history.

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## (57) ABSTRACT

The invention primarily provides gate electrodes and gate wirings permitting large-sized screens for active matrix-type display devices, wherein, in order to achieve this object, the construction of the invention is a semiconductor device having, on the same substrate, a pixel TFT provided in a display region and a driver circuit TFT provided around the display region, wherein the gate electrodes of the pixel TFT and the driver circuit TFT are formed from a first conductive layer, the gate electrodes are in electrical contact through connectors with gate wirings formed from a second conductive layer, and the connectors are provided outside the channel-forming regions of the pixel TFT and the driver circuit TFT.

#### 36 Claims, 23 Drawing Sheets

